



Substitute for form 1449B/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary)		Complete if Known			
		Application Number	10/099,927		
		Filing Date	March 13, 2002		
		First Named Inventor	Kelberlau, Ulrich		
		Art Unit	2822		
		Examiner Name	L. Kiesha Rose		
Sheet	2	of	2	Attorney Docket Number	011775-010710US

NON PATENT LITERATURE DOCUMENTS			
Examiner Initials *	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
KR	4	Ajit, "1200V High-Side Lateral MOSFET in Junction-Isolated Power IC Technology Using Two Field-Reduction Layer, IEEE (1993), pgs. 230-235.	

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Examiner Signature		Date Considered	3/9/05
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* EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹ Applicant's unique citation designation number (optional). ² Applicant is to place a check mark here if English language Translation is attached.

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